

Thyristors logic level for RCD/ GFI/ LCCB applications

BT168 series

GENERAL DESCRIPTION

Glass passivated, sensitive gate thyristors in a plastic envelope, intended for use in Residual Current Devices/ Ground Fault Interrupters/ Leakage Current Circuit Breakers (RCD/ GFI/ LCCB) applications where a minimum I_{GT} limit is needed. These devices may be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

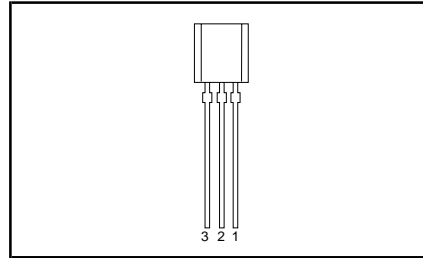
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	MAX.	UNIT
	BT168	B	D	E	G	
V_{DRM} , V_{RRM}	Repetitive peak off-state voltages	200	400	500	600	V
$I_{T(AV)}$	Average on-state current	0.5	0.5	0.5	0.5	A
$I_{T(RMS)}$	RMS on-state current	0.8	0.8	0.8	0.8	A
I_{TSM}	Non-repetitive peak on-state current	8	8	8	8	A

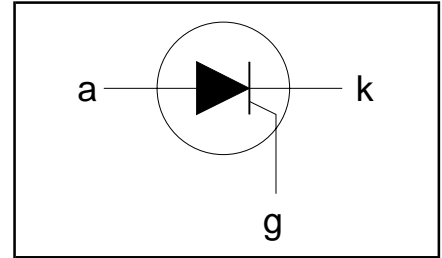
PINNING - TO92 variant

PIN	DESCRIPTION
1	anode
2	gate
3	cathode

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.				UNIT
				B	D	E	G	
V_{DRM} , V_{RRM}	Repetitive peak off-state voltages		-	200 ¹	400 ¹	500 ¹	600 ¹	V
$I_{T(AV)}$	Average on-state current	half sine wave; $T_{lead} \leq 83\text{ }^\circ\text{C}$	-	0.5				A
$I_{T(RMS)}$	RMS on-state current	all conduction angles	-	0.8				A
I_{TSM}	Non-repetitive peak on-state current	$t = 10\text{ ms}$ $t = 8.3\text{ ms}$	-	8				A
		half sine wave; $T_j = 25\text{ }^\circ\text{C}$ prior to surge	-	9				A
I^2t	I^2t for fusing	$t = 10\text{ ms}$	-	0.32				A ² s
dl_T/dt	Repetitive rate of rise of on-state current after triggering	$I_{TM} = 2\text{ A}$; $I_G = 10\text{ mA}$; $dl_G/dt = 100\text{ mA}/\mu\text{s}$	-	50				A/ μs
I_{GM}	Peak gate current		-	1				A
V_{GM}	Peak gate voltage		-	5				V
V_{RGM}	Peak reverse gate voltage		-	5				V
P_{GM}	Peak gate power		-	2				W
$P_{G(AV)}$	Average gate power	over any 20 ms period	-	0.1				W
T_{stg}	Storage temperature		-40	150				$^\circ\text{C}$
T_j	Operating junction temperature		-	125				$^\circ\text{C}$

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ μs .

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-lead}$	Thermal resistance junction to lead		-	-	60	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	pcb mounted; lead length = 4mm	-	150	-	K/W

STATIC CHARACTERISTICS

 $T_j = 25\text{ °C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{GT}	Gate trigger current	$V_D = 12\text{ V}$; $I_T = 10\text{ mA}$; gate open circuit	20	50	200	μA
I_L	Latching current	$V_D = 12\text{ V}$; $I_{GT} = 0.5\text{ mA}$; $R_{GK} = 1\text{ k}\Omega$	-	2	6	mA
I_H	Holding current	$V_D = 12\text{ V}$; $I_{GT} = 0.5\text{ mA}$; $R_{GK} = 1\text{ k}\Omega$	-	2	5	mA
V_T	On-state voltage	$I_T = 1\text{ A}$	-	1.2	1.35	V
V_{GT}	Gate trigger voltage	$V_D = 12\text{ V}$; $I_T = 10\text{ mA}$; gate open circuit	-	0.5	0.8	V
		$V_D = V_{DRM(max)}$; $I_T = 10\text{ mA}$; $T_j = 125\text{ °C}$; gate open circuit	0.2	0.3	-	V
I_D, I_R	Off-state leakage current	$V_D = V_{DRM(max)}$; $V_R = V_{RRM(max)}$; $T_j = 125\text{ °C}$; $R_{GK} = 1\text{ k}\Omega$	-	0.05	0.1	mA

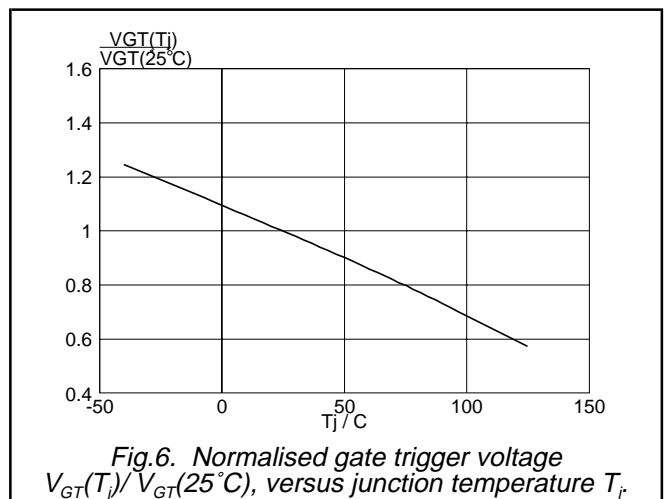
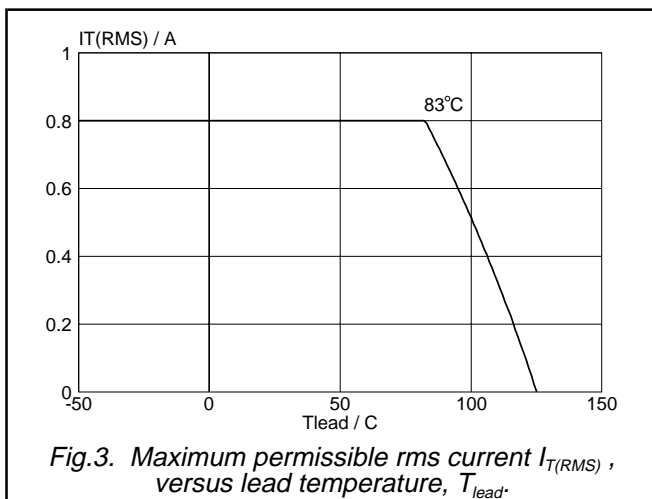
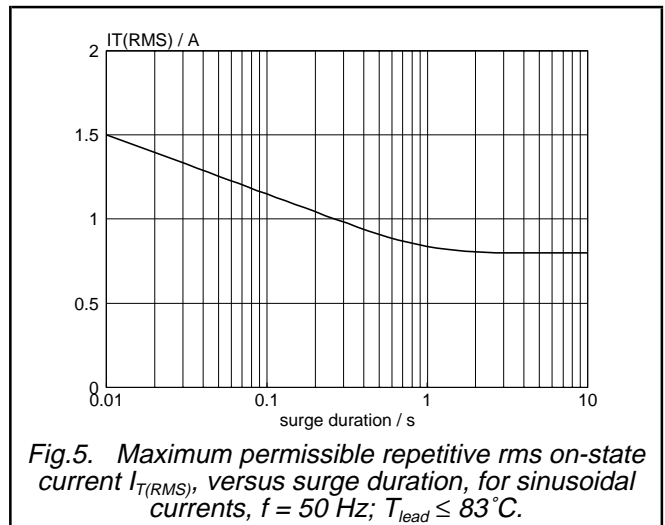
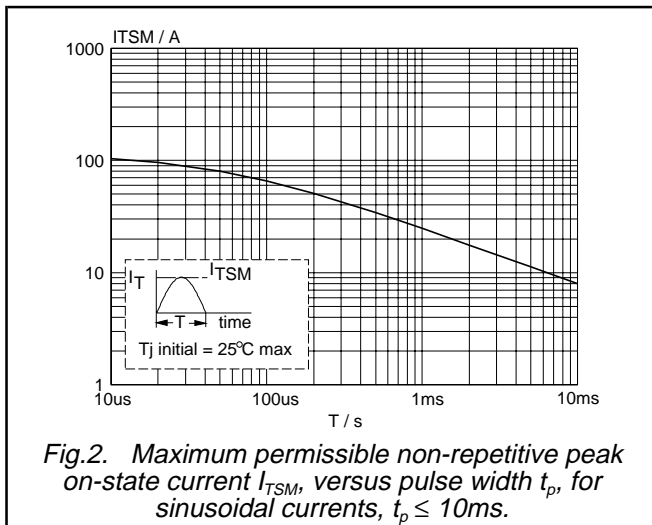
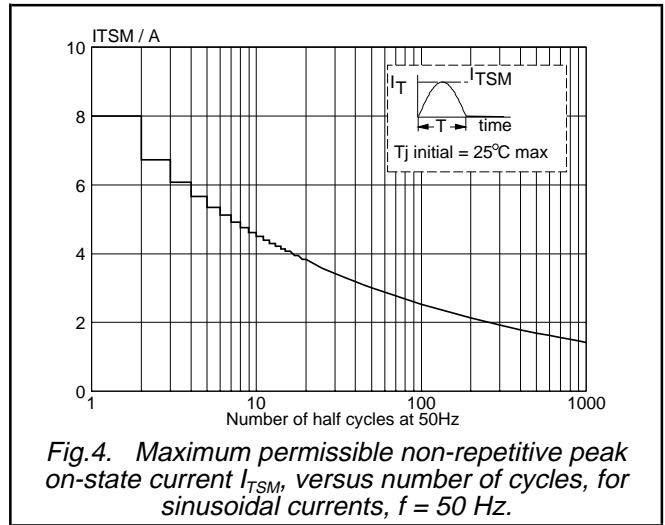
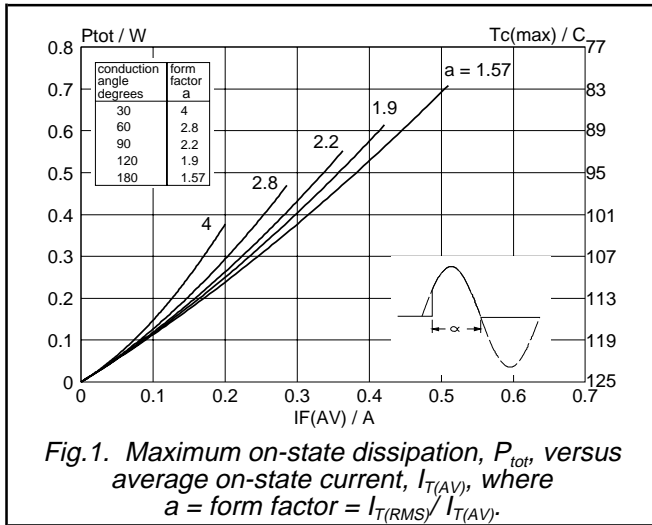
DYNAMIC CHARACTERISTICS

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV_D/dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}$; $T_j = 125\text{ °C}$; exponential waveform; $R_{GK} = 1\text{ k}\Omega$	-	25	-	V/ μs
t_{gt}	Gate controlled turn-on time	$I_{TM} = 2\text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 10\text{ mA}$; $dI_G/dt = 0.1\text{ A}/\mu\text{s}$	-	2	-	μs
t_q	Circuit commutated turn-off time	$V_D = 67\% V_{DRM(max)}$; $T_j = 125\text{ °C}$; $I_{TM} = 1.6\text{ A}$; $V_R = 35\text{ V}$; $dI_{TM}/dt = 30\text{ A}/\mu\text{s}$; $dV_D/dt = 2\text{ V}/\mu\text{s}$; $R_{GK} = 1\text{ k}\Omega$	-	100	-	μs

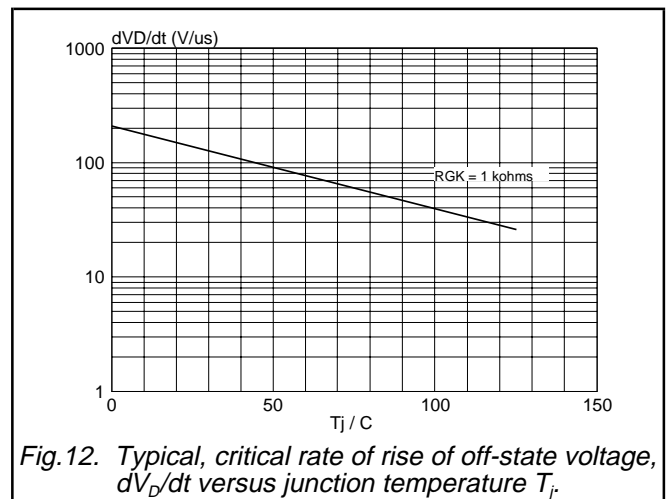
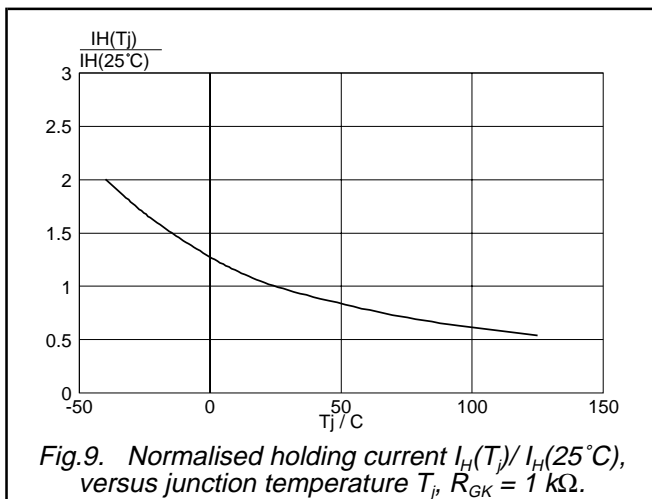
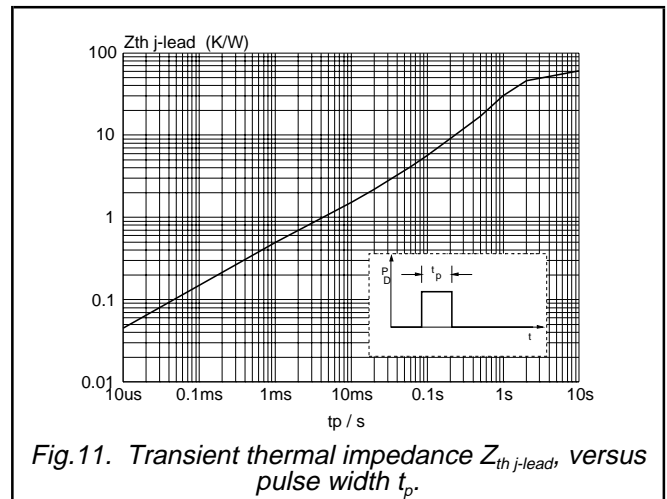
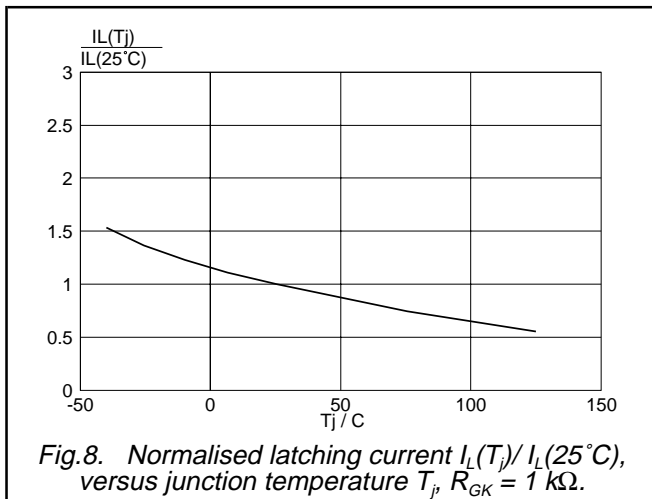
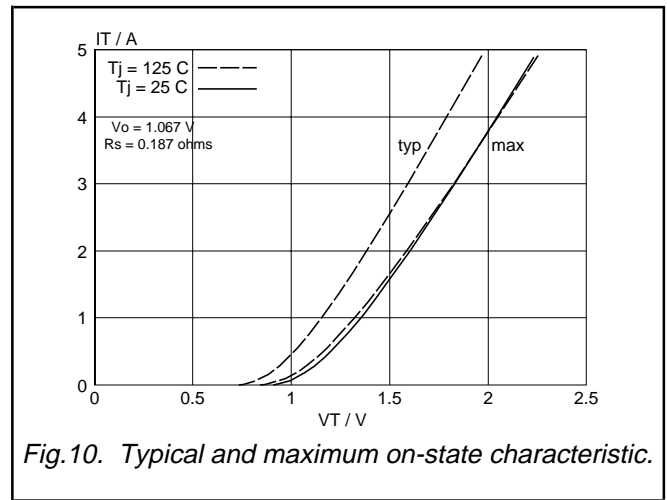
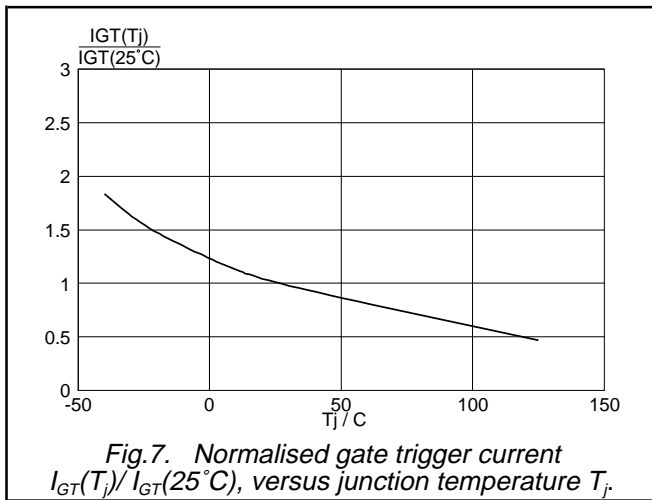
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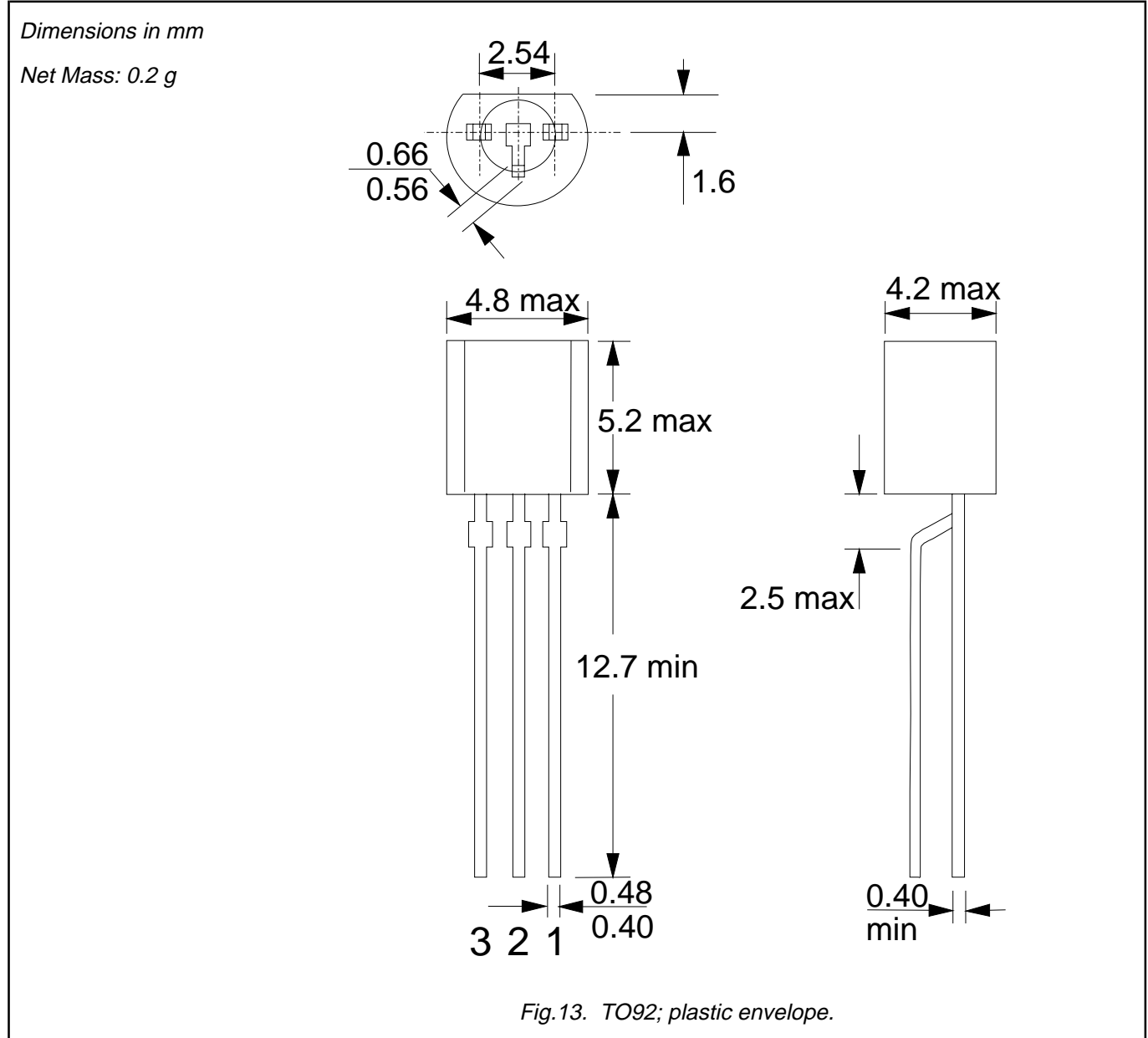
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MECHANICAL DATA



Notes

- 1. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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